TOSHIBA

Unit: mm

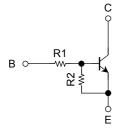
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN1701JE,RN1702JE,RN1703JE RN1704JE,RN1705JE,RN1706JE

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

- Two devices are incorporated into an Extreme-Super-Mini (5 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count. Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Wide range of resistor values are available to use in various circuit designs.
- Complementary to RN2701JE~2706JE

Equivalent Circuit and Bias Resistor Values

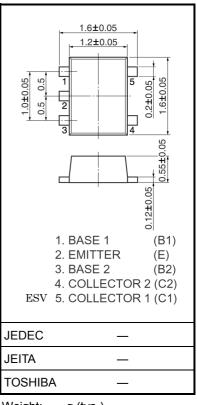


Type No.	R1 (kΩ)	R2 (kΩ)
RN1701JE	4.7	4.7
RN1702JE	10	10
RN1703JE	22	22
RN1704JE	47	47
RN1705JE	2.2	47
RN1706JE	4.7	47

Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

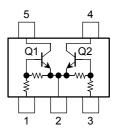
Characteristics	Symbol	Rating	Unit		
Collector-base voltage	RN1701JE~	V _{CBO}	50	V	
Collector-emitter voltage	1706JE	V _{CEO}	50	V	
Emitter have voltage	RN1701JE~ 1704JE		10	V	
Emitter-base voltage	RN1705JE, RN1706JE	V _{EBO}	5		
Collector current		Ι _C	100	mA	
Collector power dissipation	RN1701JE~ 1706JE	P _C (Note)	100	mW	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Total rating



Weight: g (typ.)

Equivalent Circuit (top view)



Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1701JE~1706JE	I _{CBO}	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0$			100	nA
		ICEO	$V_{CE}=50~V,~I_B=0$		_	500	
	RN1701JE	ІЕВО	V _{EB} = 10 V, I _C = 0	0.82	_	1.52	mA
	RN1702JE			0.38	_	0.71	
Emitter cut-off current	RN1703JE			0.17	_	0.33	
Emilier cut-on current	RN1704JE			0.082	_	0.15	
	RN1705JE		$V_{EB} = 5 V, I_{C} = 0$	0.078	_	0.145	
	RN1706JE			0.074	_	0.138	
	RN1701JE		V _{CE} = 5 V, I _C = 10 mA	30	_		
	RN1702JE			50	_		
DC ourront goin	RN1703JE	h _{FE}		70	_		
DC current gain	RN1704JE			80	_		
	RN1705JE			80	_		
	RN1706JE			80	_		
Collector-emitter saturation voltage	RN1701JE~1706JE	V _{CE (sat)}	$I_C = 5 \text{ mA},$ $I_B = 0.25 \text{ mA}$	_	0.1	0.3	V
	RN1701JE	VI (ON)	$V_{CE} = 0.2 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$	1.1		2.0	V
	RN1702JE			1.2	_	2.4	
	RN1703JE			1.3	_	3.0	
Input voltage (ON)	RN1704JE			1.5	_	5.0	
	RN1705JE			0.6	_	1.1	
	RN1706JE			0.7	_	1.3	
	RN1701JE~1704JE		$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 0.1 \text{ mA}$	1.0	_	1.5	v
Input voltage (OFF)	RN1705JE, 1706JE	V _{I (OFF)}		0.5	_	0.8	
Transition frequency	RN1701JE~1706JE	f _T	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$		250		MHz
Collector output capacitance	RN1701JE~1706JE	C _{ob}	$\begin{array}{l} V_{CB}=10 \ V, \ I_{E}=0, \\ f=1 \ MHz \end{array}$	_	3	6	pF
	RN1701JE	- R1		3.29	4.7	6.11	kΩ
	RN1702JE			7	10	13	
land the state of	RN1703JE			15.4	22	28.6	
Input resistor	RN1704JE			32.9	47	61.1	
	RN1705JE			1.54	2.2	2.86	
	RN1706JE			3.29	4.7	6.11	
	RN1701JE~1704JE	R1/R2	_	0.9	1.0	1.1	
Resistor ratio	RN1705JE			0.0421	0.0468	0.0515	-
	RN1706JE	1		0.09	0.1	0.11	

Type Name	Marking
RN1701JE	XA XA
RN1702JE	Type name XB
RN1703JE	Type name XC
RN1704JE	Type name X D
RN1705JE	Type name XE
RN1706JE	Type name X F

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